

#### Features

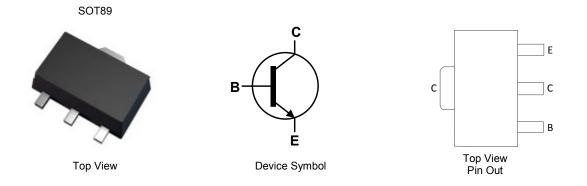
- BV<sub>CEO</sub> > 25V
- I<sub>C</sub> = 5.5A Continuous Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < 0.2V @ 6.5A</li>
- $R_{sat} = 25m\Omega$  for a Low Equivalent On-Resistance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

## **Mechanical Data**

- Case: SOT89
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.05 grams (Approximate)

### Application

- Emergency lighting circuits
- Motor driving (including DC fans)
- Solenoid, relay and actuator drivers
- DC modules
- Backlight Inverters



## Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity Per Reel
ZXTN2005ZTA	Standard	869	7	12	1,000

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**

Notes:





# Absolute Maximum Ratings (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	25	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	Ιc	5.5	A
Peak Pulse Collector Current (single pulse)	Ісм	20	A

# Thermal Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

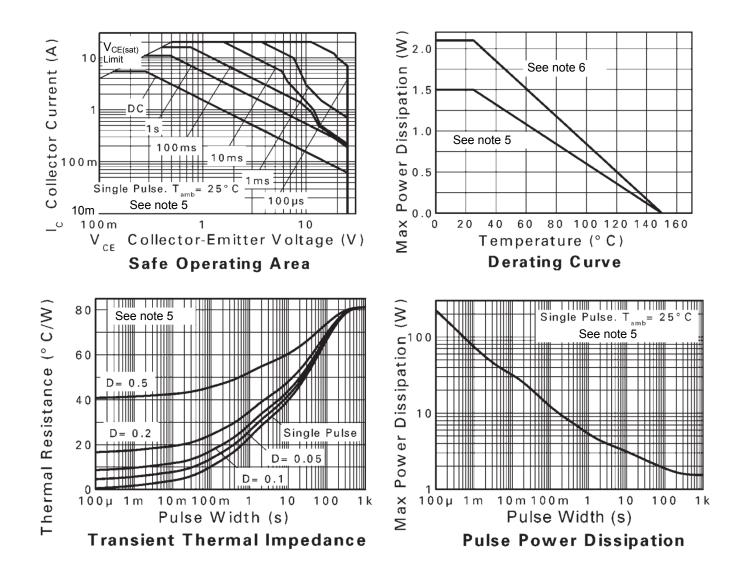
Characteristic	Symbol	Value	Unit	
Power Dissipation (Note 5) Linear Derating Factor		1.5 12	W	
Power Dissipation (Note 6) Linear Derating Factor	PD PD	2.1 16.8	mW/°C	
Thermal Resistance, Junction to Ambient (Note 5)	Devi	83	°C/W	
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>0JA</sub>	60		
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C	

Notes: 5. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; device measured when operating in steady state condition.

6. Same as note (5), except the device is mounted on 50mm x 50mm x 1.6mm single sided 2oz weight copper.



# **Thermal Characteristics and Derating Information**





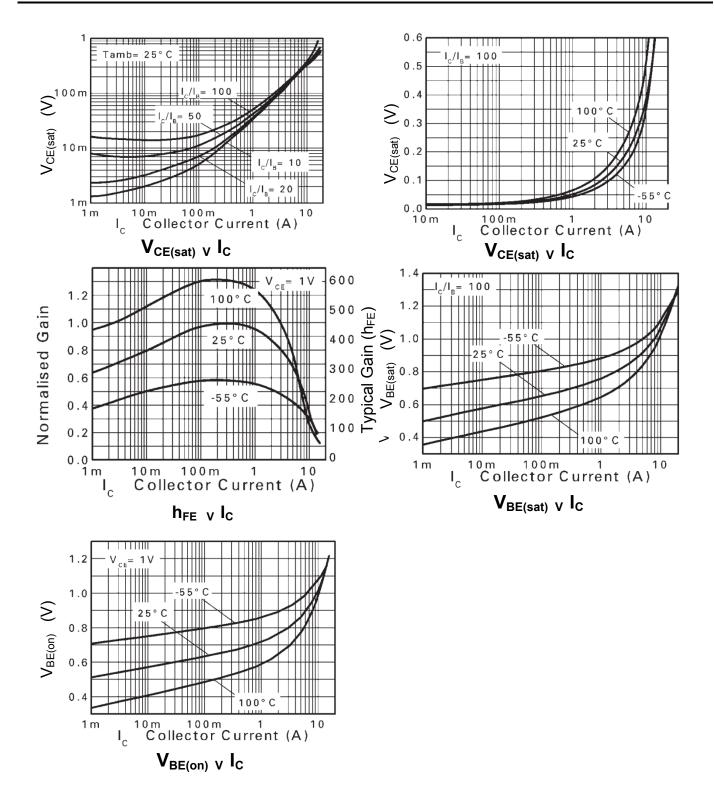
# Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV <sub>CBO</sub>	60	120	_	V	I <sub>C</sub> = 100μA
Collector-emitter breakdown voltage	BV <sub>CER</sub>	60	120	_	V	I <sub>C</sub> = 1μΑ, R <sub>BE</sub> ≤ 1kΩ
Collector- Emitter Breakdown Voltage (Note 7)	BV <sub>CEO</sub>	25	35	_	V	I <sub>C</sub> = 10mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7.0	8.1	_	V	I <sub>E</sub> = 100μA
Collector Base Cut-Off Current	I <sub>CBO</sub>	_	_	20 0.5	nA μA	V <sub>CB</sub> = 50V V <sub>CB</sub> = 50V, T <sub>A</sub> = +100°C
Collector Emitter Cut-Off Current	I <sub>CER</sub> R≤1kΩ	_	_	20 0.5	nA μA	V <sub>CB</sub> = 50V V <sub>CB</sub> = 50V, Tamb=100°C
Emitter Cut-Off Current	I <sub>EBO</sub>	—	—	10	nA	V <sub>EB</sub> = 6V
Collector-Emitter Saturation Voltage (Note 7)	V <sub>CE(sat)</sub>	_	25 30 45 105 160	35 45 70 130 200	mV	$I_{C} = 500$ mA, $I_{B} = 10$ mA $I_{C} = 1$ A, $I_{B} = 10$ mA $I_{C} = 1$ A, $I_{B} = 10$ mA $I_{C} = 2$ A, $I_{B} = 10$ mA $I_{C} = 6.5$ A, $I_{B} = 150$ mA
Base-Emitter Saturation Voltage (Note 7)	V <sub>BE(sat)</sub>	_	950	1050	mV	I <sub>C</sub> = 6.5A, I <sub>B</sub> = 150mA
Base-Emitter Turn-On Voltage (Note 7)	V <sub>BE(on)</sub>	_	860	960	mV	I <sub>C</sub> = 6.5A, V <sub>CE</sub> = 1V
DC Current Gain (Note 7)	hfe	300 300 200 40	400 450 275 55	_	_	$I_{C} = 10mA, V_{CE} = 1V$ $I_{C} = 1A, V_{CE} = 1V$ $I_{C} = 7A, V_{CE} = 1V$ $I_{C} = 20A, V_{CE} = 1V$
Transitional frequency	f <sub>T</sub>	_	150	_	MHz	I <sub>C</sub> = 100mA, V <sub>CE</sub> = 10V, f = 50MHz
Output Capacitance	Cobo	—	48	_	pF	V <sub>CB</sub> = 10V, f = 1MHz
Switching times	t <sub>on</sub> t <sub>off</sub>		33 464	_	ns	$V_{CC} = 10V$ $I_C = 1A$ , $I_{B1} = -I_{B2} = 100mA$

Note: 7. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.



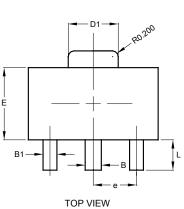
# Typical Electrical Characteristics (@ T<sub>A</sub> = +25°C, unless otherwise specified.)

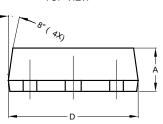


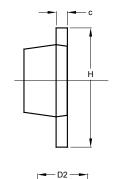


# Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

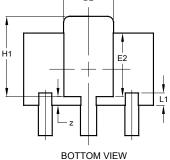






SOT89

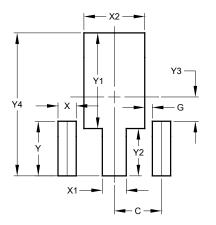




SOT89						
Dim	Min	Max	Тур			
Α	1.40	1.60	1.50			
В	0.50	0.62	0.56			
B1	0.42	0.54	0.48			
С	0.35	0.43	0.38			
D	4.40	4.60	4.50			
D1	1.62	1.83	1.733			
D2	1.61	1.81	1.71			
Е	2.40	2.60	2.50			
E2	2.05	2.35	2.20			
е	-	-	1.50			
Н	3.95	4.25	4.10			
H1	2.63	2.93	2.78			
L	0.90	1.20	1.05			
L1	0.327	0.527	0.427			
z	0.20	0.40	0.30			
All	All Dimensions in mm					

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value		
•	(in mm)		
C	1.500		
G	0.244		
X	0.580		
X1	0.760		
X2	1.933		
Y	1.730		
Y1	3.030		
Y2	1.500		
Y3	0.770		
Y4	4.530		

**SOT89** 



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